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Iwasaki

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[EA]	EXTERNAL	CTODACE	DEVICE
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[75] Inventor: Hiroshi Iwasaki, Yokohama, Japan

[73] Assignee: Kabushiki Kaisha Toshiba, Kawasaki,

Japan

[*] Notice:

This patent issued on a continued prosecution application filed under 37 CFR 1.53(d), and is subject to the twenty year patent term provisions of 35 U.S.C. 154(a)(2).

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This patent is subject to a terminal dis-

claimer.

[21] Appl. No.: 08/818,575

[22] Filed: Mar. 14, 1997

Related U.S. Application Data

[60] Continuation of application No. 08/657,383, Jun. 3, 1996, which is a division of application No. 08/205,451, Mar. 4, 1994, Pat. No. 5,550,709.

[30] Foreign Application Priority Data

Jul. 23, 1993 [JP] Japan 5-182650

[51] Int. Cl.⁷ H05K 5/00

746, 750, 762, 783, 795; 257/679; 235/492

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Primary Examiner—Jeffrey Gaffin

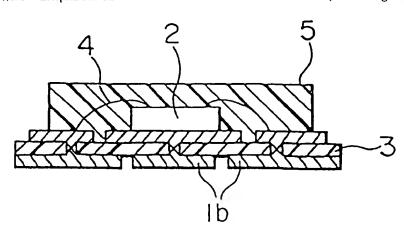
Assistant Examiner-Tuan Dinh

Attorney, Agent, or Firm—Finnegan, Henderson, Farabow, Garrett & Dunner, L.L.P.

[57] ABSTRACT

An external storage device includes an external storage device main includes a thin-type external storage device module formed into a package sealed on one side-from a storage element containing at least one non-volatile semi-conductor memory device, and a flat-type external connection terminal connected to an input/output terminal of the storage element and led and exposed to a backside of the module, and an external storage device unit that includes an external storage device unit main detachable section engaging, insertedly attaching, and detaching the external storage device main, a resilient contact electrically connecting—to—the—external connection terminal of the external storage device main, and at least a part of a circuit for driving and controlling the storage element.

4 Claims, 4 Drawing Sheets



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FIG. I

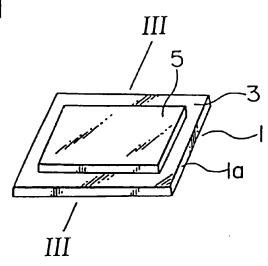


FIG. 2

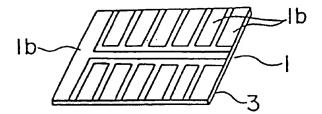


FIG. 3

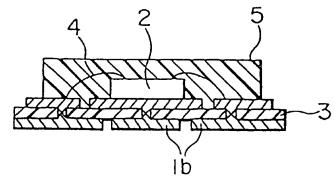


FIG. 4

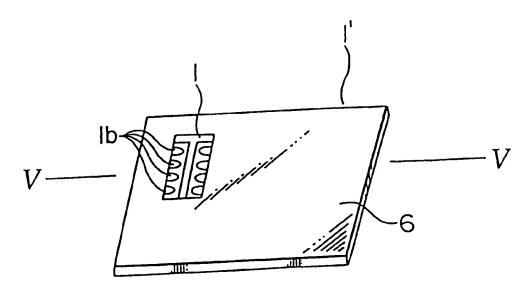


FIG. 5

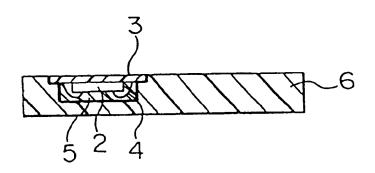


FIG. 6

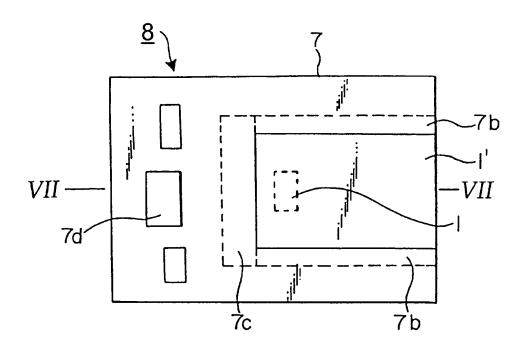


FIG. 7

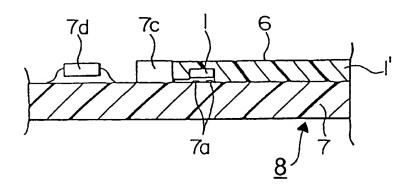


FIG. 8

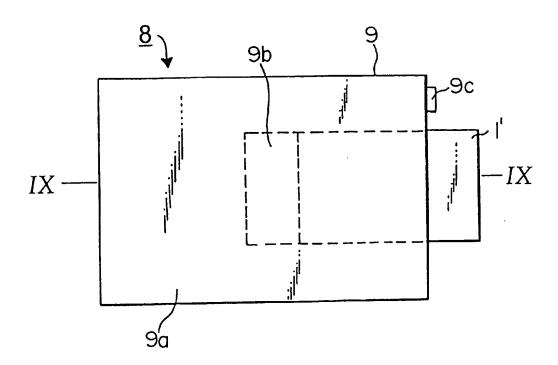
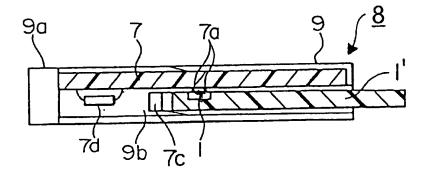


FIG. 9



EXTERNAL STORAGE DEVICE

This is a continuation of application Ser. No. 08/657,383, filed Jun. 3, 1996, which is a divisional application of application Ser. No. 08/205,451, filed Mar. 4, 1994 now U.S. 5 Pat. No. 5,550,709.

BACKGROUND OF THE INVENTION

1. Field of the Invention

The present invention relates to this external storage 10 devices that are releasably or exchangeably used for storage equipment and external storage medium devices.

2. Description of the Related Art

Two types of storage devices, or memory elements, that are capable of recording and saving various data have been utilized. One is incorporated and fixed within storage equipment or devices, and the other is releasably or exchangeably incorporated in storage equipment or devices. In the latter type, the external storage device, for example, floppy disk, can freely be attached or detached by a one touch operation. The floppy disks, being storage mediums, can separately be used depending on purpose and object. This therefore produces easier data reduction with optional classification, recording, and saving. However, a problem arises in the floppy disks described. First, the data occasionally disappear when recording or saving the data to produce the disadvantage of less reliability. Second the floppy disk has a slow access time. Also, when employing smaller sized floppy disks in response to a miniaturization goal, the storage area of the storage medium is correspondingly smaller thereby reducing storage capacity. This thus gives an adverse effect in realizing both the compact size and high capacity. On the other hand, in semiconductor memory devices used as an external storage device, such as IC memory cards, the problems of the floppy disks, such as low reliability on recording and saving data and slow access time can largely be overcome. In general, IC memory cards comprise a functional circuit in which circuit components containing semiconductor memory devices or elements are mounted on a substrate. A resin case incorporates the functional circuit as an inside attachment. A cover covers and seals an opening surface of the resin case, and external connection terminals, such as two piece connectors, are attached on one edge of the resin case and electrically connect the functional circuit and the storage equipment.

However, IC memory cards are assembled with a large number of components and parts. Thus a relatively complicated structure is required impacting the thickness of the IC memory card, resulting in difficulty in realizing a compact 50 disconnecting due to the attaching and detaching size. Further, disadvantages arise in practical use because of lower cost performance and production yields in mass producing, in addition to the decreased releasability or fluctuated releasability to the storage equipment and device.

SUMMARY OF THE INVENTION

An object of the present invention is to provide an external storage device having a simplified structure with satisfactory production yields.

Another object of the present invention is to provide an 60 external storage device with a high reliability with respect to recording and saving the data.

Another object of the present invention is to provide an external storage device having a rapid access time.

Still another object of the present invention is to provide 65 an external storage device having high releasability for the storage equipment and device.

The external storage device according to the present invention comprises an external storage device main and an external storage device unit. The external storage device main includes, a thin external storage device module formed into a package scaled on one side from a storage element containing at least one non-volatile semiconductor memory device, and a flat type external connection terminal connected to an input/output terminal of the storage element and led and exposed to a backside of the external storage device module. The external storage device unit includes a mechanism for engaging, insertedly attaching, and detaching the external storage device main, a resilient contact electrically connecting to the flat type external connection terminal of the external storage device main.

In the external storage device according to the present invention, the external storage device main may preferably be formed into a package structure sealed on one side. However for easier handling, the external storage device main may also preferably be in the form of a card type structure attached on a supporting plate. The external storage device unit may preferably be assembled and incorporated with a part of or all of the control circuit components or parts, such as semiconductor elements, performing the control function.

The external storage device of a preferred embodiment has a higher integration with a memory capacity to an extent of 16 M-bits per chip. In addition, the storage device is preferably provided as a main memory with a non-volatile semiconductor memory device which does not require a power supply for maintaining storage. The main memory is incorporated into the package sealed on one side to produce a thin type external storage device module or external storage device main. Thus, the external storage device module is easily achieved in a thin structure and at a lower cost by, for example a transfer mold system. To mount a card type external storage device main to the external storage device unit, an insertion system at the side surface of the external storage device unit may be provided. An external connection terminal is led and positioned in a plane with a rear-side of the external storage device main. Hence, a highly reliable electrical connection can easily be achieved when attaching and detaching by a one touch system the external storage device unit. In a card type device, the external storage device itself maintains and exhibits satisfactory releasability for the storage equipment and devices. The card type external storage device main can readily be attached and detached to the external storage device unit, and realizes a function equivalent to a floppy disk device, and simultaneously a reliability of electrical connecting and

BRIEF DESCRIPTION OF THE DRAWINGS

FIG. 1 is a top perspective view of first example of an external storage device main according to the present inven-

FIG. 2 is a bottom perspective view of an example of the first external storage device main shown in FIG. 1.

FIG. 3 is an enlarged sectional view taken along line III—III of FIG. 1.

FIG. 4 is a top perspective view of a second example of an external storage device main according to the present invention.

FIG. 5 is an enlarged sectional view taken along line V—V of FIG. 4.

FIG. 6 is a plan view of an example of an external storage device in which the external storage device main shown in FIG. 4 is assembled onto an external storage device unit.

FIG. 7 is a sectional view taken along line VII—VII of

FIG. 8 is a plan view of an example of another external storage device in which the external storage device main shown in FIG. 7 is assembled into an external storage device 5

FIG. 9 is a sectional view taken along line IX—IX of FIG. 8.

DESCRIPTION OF THE PREFERRED **EMBODIMENTS**

Embodiments of invention are described referring to FIGS. 1 to 9 as follows.

The present invention has been achieved by means of a cleverly conceived structure and profile where the devices such as semiconductor memory devices or elements are mounted on the conventional substrates and in accordance with the fact that a non-volatile semiconductor memory device or element with a capacity of 16 M-bits per chip corresponds to a 2 M-byte floppy disk.

FIGS. 1 to 3 show a first example of an external storage device module constituting features of the thin type external storage device main according to the invention, where FIG. 1 is a perspective view on surface which is one-sided sealed on one side by a transfer mold, FIG. 2 a perspective view of 25 a rear-side surface which is one-side sealed by the transfer mold, and FIG. 3 is a sectional view taken along line III—III of FIG. 1.

In this first example, a card type external storage device as a 16 M-bit NAND flash type non-volatile semiconductor memory device, is connected on a surface of the through hole type resin based wiring substrate 3 by wire-bonding 4. The storage element 2 may, if required, include an antielectrostatic element for preventing electrostatic destruction, 35 the anti-electrostatic element being used for input and output to the memory element 2. Instead of the wire bonding 4, flip chip bonding may also be performed to directly adhere the rear side of the memory element 2 on the resin based wiring substrate 3 which the substrate 3 is preferably a thin wiring 40 substrate, for example, an insulative substrate member made of glass-epoxy resin or the like. The resin based wiring substrate 3, a surface on which is mounted the storage element 2 including a NAND flash type non-volatile semiconductor memory device 8, is sealed on one side by a 45 transfer mold layer 5. More specifically, the external storage device module 1 (which is designated the external storage device main when considered by itself) is sealed on one side and formed into a flat plate shaped thin type package with an layer 5 may generally be formed of epoxy based resin or the like. However, it also may preferably be formed of a composition containing inorganics.

On the other hand, the one-side sealed through hole type resin based wiring substrate 3, in other words, the backside 55 surface 1a of the external storage device module 1 is arranged with a plane shaped or flat type terminal 1b taken out through the through hole to form the external storage device modula 1. The plane shaped terminal 1b is preferably connection terminal for electrically connecting to a contact member of an external storage device unit which is described later. In this example, the plane shaped terminal 1b is gold-plated to increase the reliability of the electrical connection. However, such plating is not always required.

FIGS. 4 and 5 show a second structural example of the card type external storage device main 1' in which the

external storage device module is attached on a card shaped supporter 6, where FIG. 4 is a perspective view, and FIG. 5 is a sectional view taken along line V—V of FIG. 4. The card shaped supporter 6 may preferably be, for example, an insulative resin plate.

In the second example above, for a simplified operation the external storage device module 1 is incorporated into the card shaped supporter 6 having a length of 42.8 mm, a width of less than 27 mm, and a thickness of 0.76 mm, wherein the size of the supporter 6 is half the card size regulated in accordance with JEIDA. In more detail, the external storage device module 1 is assembled into the card shaped supporter 6. The supporter 6 has a recessed portion in which the external storage device module 1 can be inserted and 15 attached. As shown in FIGS. 4 and 5, a surface of the external connection terminal 1b of the external storage device module 1 is inserted, attached and an exposed in the same plane as a main surface of the card shaped supporter 6, thereby forming the card type storage device main 1'.

FIGS. 6 and 7 show a structural example wherein the card type external storage device main 1' is attached to an external storage device unit 7, where FIG. 6 is a plan view, and FIG. 7 is a sectional view taken along line VII-VII of

In this example, the card type external storage device main 1' has storage elements on one side thereof. The external storage device module 1, in which the storage element 2 including at least a non-volatile semiconductor memory chip is sealed on one side by the transfer mold layer module 1 is constructed such that a storage element 2, such 30 5, is inserted and attached into the card shaped supporter 6 to produce the card type external storage device main 1'. The card type external storage device main 1' is releasably attached on and installed into the external storage device unit 7 to form an external storage device 8. The external storage device unit 7 can be electrically connected to the plane shaped external connection terminal 1b provided on the external storage device module 1 on the card type external storage device main 1'. Simultaneously the external storage device unit 7 has a structure that the card type external storage device main 1' is releasably attached there

To releasably attach, and detach the card type external storage device main 1' is the external storage device unit 7 has on its surface a recessed portion corresponding to the shape and dimensions of the card type external storage device main 1'. A surface on the recessed portion is arranged with a contact 7a that preferably corresponds to the external connection terminal 1b of the card type external storage device main 1'. To attach and detach the card type external entire thickness of less than about 1 mm. The transfer mold 50 storage device main 1' smoothly, a guide structure 7b and a one touch structure 7c are preferably provided. When the card type external storage device main 1' is inserted, attached or removed from the external storage device unit 7, a smooth insertion and extraction is provided by the guide structure 7b which is placed on a side-surface of the unit 7 in the insertion and extraction direction. Simultaneously, the one touch structure 7c is preferably placed at a tip end of card 1 and provides secure attaching electrical connection, and releases thereof. If required, a micro-switch system for gold (Au)-plated on its surface, and functions as an external 60 supplying electricity to the card type external storage device main 1' may preferable be provided with the one touch structure 7c. In FIGS. 6 and 7, element 7d represents an IC element group constituting a part of a drive and control circuit for the storage element 2 including the non-volatile semiconductor memory chip, which the card type external storage device section 1' possesses. The contact 7a for electrically connecting to the external connection terminal 5

1b is made, for example, using a pin type contact having a spring mechanism.

The external storage device 8, including the card type external storage device main 1', according to the present 5 invention is not limited to the example as described above. For example, the present invention also including the structure shown in a plan view of FIG. 8 and in a sectional view of FIG. 9 taken along line IX—IX of FIG. 8. The card type external storage device main 1' may preferably be inserted or 10 extracted from a side-surface of a case 9. The case 9 preferably has one side a pin connection 9a. The case 9 may, for example, be sized to have a length of 85.6 mm, a width of 54.0 mm, and a thickness of 3.3 mm. In more detail, the case 9 is also preferably provided with an insertion and 15 extraction section 9b such as a space or gap, for attaching, through inserting and extracting, the card type external storage device main 1' from the side-surface of the case 9. A push button 9c may preferably be provided on the case 9 to achieve attaching or detaching to the external storage 20 device unit 7. In particular, when the card type external storage device main 1' is attached by inserting and extracting from the side surface of the external storage device unit 7, compared to a structure having a surface recessed portion for 25 attaching the card type external storage device main 1', it is correspondingly not required to enlarge an outer surface required for attaching the external storage device. Thus, this easily realizes a compact size, fine view, and high reliability due to incorporation (inside mount) of the card type external 30 storage device main 1'.

It is understood that the present invention is not limited to the examples as hereinbefore described. For example, the card type external storage device main 1 according to the present invention may be used, as it is, without attaching it 35 on or to the card shaped supporter 6.

As is apparent from the description above, the external storage device according to the present invention has a higher integration and provides, even in one chip, a larger 40 memory capacity of a non-volatile semiconductor memory device as a main memory. In addition, basic construction is employed in that the external storage device main has a compact structure, and the main memory is sealed on one side, by a transfer mold. The use of the one-side sealing $_{45}$ system and the non-volatile semiconductor memory device provides a thin structure and compact size of the external storage device. The releasable attaching and ease of carrying provide simple operation and handling, and result in a lower cost. When forming the external storage device by combining with the external storage device unit, reliability in the card type external storage device can be improved, thereby preventing damage or connection failures of the external connection terminal with a graded releasability due to satisfactory slidability. A great number of advantages in practical use are obtained, such as optionally detaching or easily carrying the external storage device main without the possibility of external damage, and a larger capacity of recording or saving data even given the compact size.

What is claimed is:

1. An external storage device comprising:

an external storage device main including,

- a thin type external storage device module comprising a storage element containing at least one non-volatile semiconductor memory device into which data to be stored is serially input and which serially outputs data and which is formed into a package resin sealed on one side, and
- a flat type external connection terminal connected to an input/output terminal of the storage element and led and exposed to a backside of the thin type external storage device module; and

an external storage device unit including,

means for engaging, insertedly and rigidly attaching and detaching the external storage device main,

a resilient contact electrically connecting to the flat type external connection terminal of the external storage device main, and

means for driving and controlling the storage element.

- 2. The external storage device as claimed in claim 1, wherein the non-volatile semiconductor memory device of the external storage device main is a NAND flash memory that serially inputs data to be stored and serially outputs data.
- 3. The external storage device as claimed in claim 1, wherein the means for driving and controlling the storage element drives and controls the storage element so that the storage element serially inputs data to be stored and serially outputs data.
 - 4. An external storage device comprising:

an external storage device main including,

- a thin type external storage device module comprising a substrate having a first face and a second face,
- a storage element containing at least one non-volatile semiconductor memory into which data to be stored is serially input and which serially outputs data and has input/output terminals formed on the second face of the substrate, wherein the storage element is resin sealed on one side in the first face of the substrate,
- a flat type external connection terminal connected to the input/output terminals of the storage element,
- a card shaped supporter having a surface and having a recess for placement of the thin type external storage device module so that the second face of the substrate is exposed to the surface of the supporter and so that a surface of the flat external connection terminal is substantially flush with the surface of the supporter; and

an external storage device unit including,

- means for engaging, insertedly and rigidly attaching and detaching the external storage device main,
- a resilient contact electrically connecting to the flat type external connection terminal of the external storage device main, and
- means for driving and controlling the storage element, so that the storage element serially inputs data to be stored and serially outputs data.

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